

## Complementary power Darlingtons

Datasheet — production data

### Features

- Monolithic Darlingtons configuration
- Integrated antiparallel collector-emitter diode

### Applications

- Linear and switching industrial equipment

### Description

The devices are manufactured in planar technology with “base island” layout and monolithic Darlingtons configuration. The resulting transistors show exceptional high gain performance coupled with very low saturation voltage.

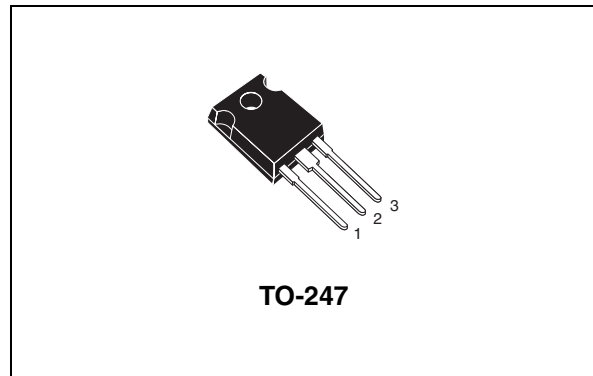


Figure 1. Internal schematic diagrams

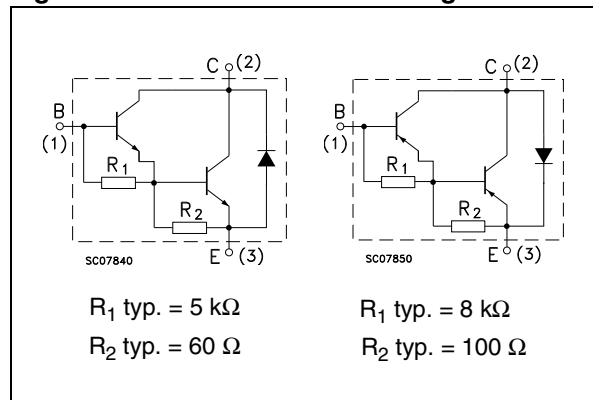


Table 1. Device summary

Part number	Marking	Polarity	Package	Packaging
TIP142	TIP142	NPN	TO-247	Tube
TIP147	TIP147	PNP		

# 1 Absolute maximum ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base voltage ( $I_E = 0$ )	100	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	100	V
$V_{EBO}$	Emitter-base voltage ( $I_C = 0$ )	5	V
$I_C$	Collector current	10	A
$I_{CM}$	Collector peak current	20	A
$I_B$	Base current	0.5	A
$P_{TOT}$	Total dissipation at $T_{case} = 25\text{ °C}$	125	W
$T_{STG}$	Storage temperature	-65 to 150	°C
$T_J$	Max. operating junction temperature	150	°C

*Note:* For PNP type voltage and current are negative.

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thJC}$	Thermal resistance junction-case	max 1	°C/W

## 2 Electrical characteristics

$T_{\text{case}} = 25\text{ }^{\circ}\text{C}$ ; unless otherwise specified.

**Table 4. Electrical characteristics**

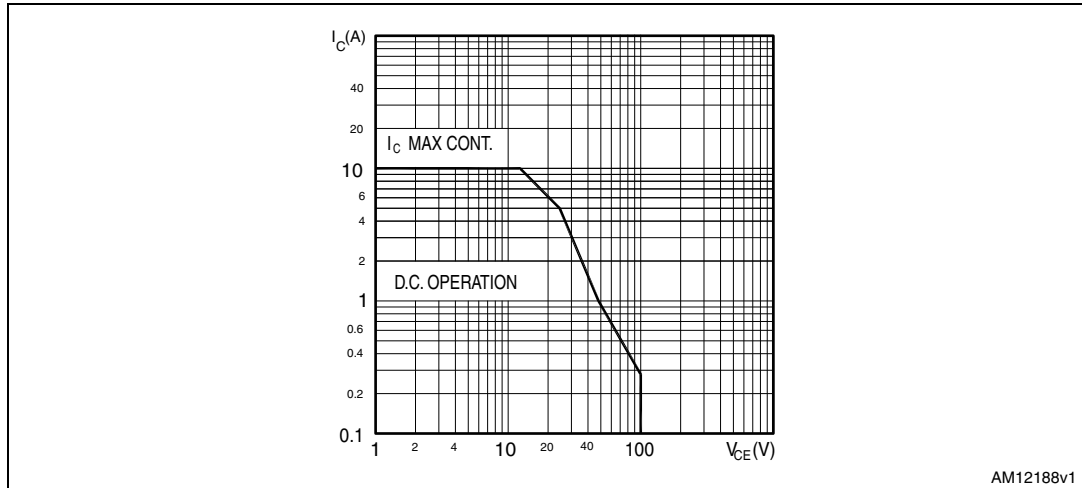
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{\text{CBO}}$	Collector cut-off current ( $I_{\text{E}} = 0$ )	$V_{\text{CB}} = 100\text{ V}$			1	mA
$I_{\text{CEO}}$	Collector cut-off current ( $I_{\text{B}} = 0$ )	$V_{\text{CE}} = 50\text{ V}$			2	mA
$I_{\text{EBO}}$	Emitter cut-off current ( $I_{\text{C}} = 0$ )	$V_{\text{EB}} = 5\text{ V}$			2	mA
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ( $I_{\text{B}} = 0$ )	$I_{\text{C}} = 30\text{ mA}$	100			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 5\text{ A}$ $I_{\text{B}} = 10\text{ mA}$ $I_{\text{C}} = 10\text{ A}$ $I_{\text{B}} = 40\text{ mA}$			2 3	V V
$V_{\text{BE(on)}}^{(1)}$	Base-emitter on voltage	$I_{\text{C}} = 10\text{ A}$ $V_{\text{CE}} = 4\text{ V}$			3	V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 5\text{ A}$ $V_{\text{CE}} = 4\text{ V}$ $I_{\text{C}} = 10\text{ A}$ $V_{\text{CE}} = 4\text{ V}$	1000 500			
$t_{\text{on}}$ $t_{\text{off}}$	Resistive load Turn-on time Turn-off time	$I_{\text{C}} = 10\text{ A}$ $R_{\text{L}} = 3\text{ }\Omega$ $I_{\text{B1}} = -I_{\text{B2}} = 40\text{ mA}$		0.9 4		$\mu\text{s}$ $\mu\text{s}$

1. Pulse test: pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .

For PNP type voltage and current are negative.

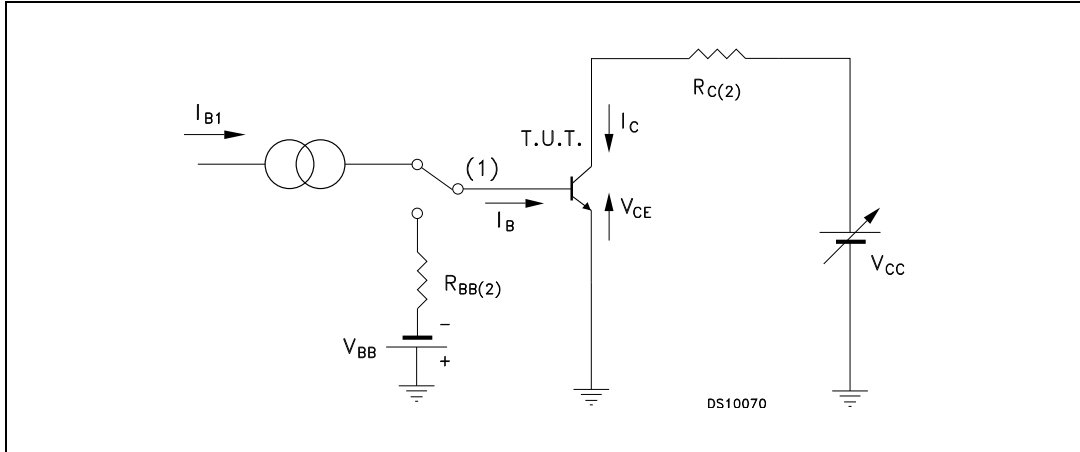
### 3 Electrical characteristics (curve)

Figure 2. Safe operating area



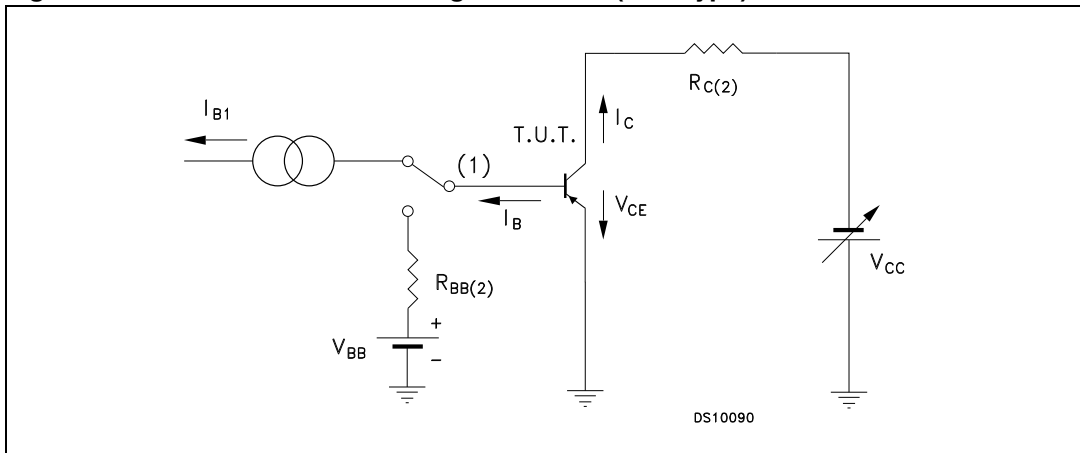
## 4 Test circuits

**Figure 3. Resistive load switching test circuit (NPN type)**



1. Fast electronic switch
2. Non-inductive resistor

**Figure 4. Resistive load switching test circuit (PNP type)**



1. Fast electronic switch
2. Non-inductive resistor

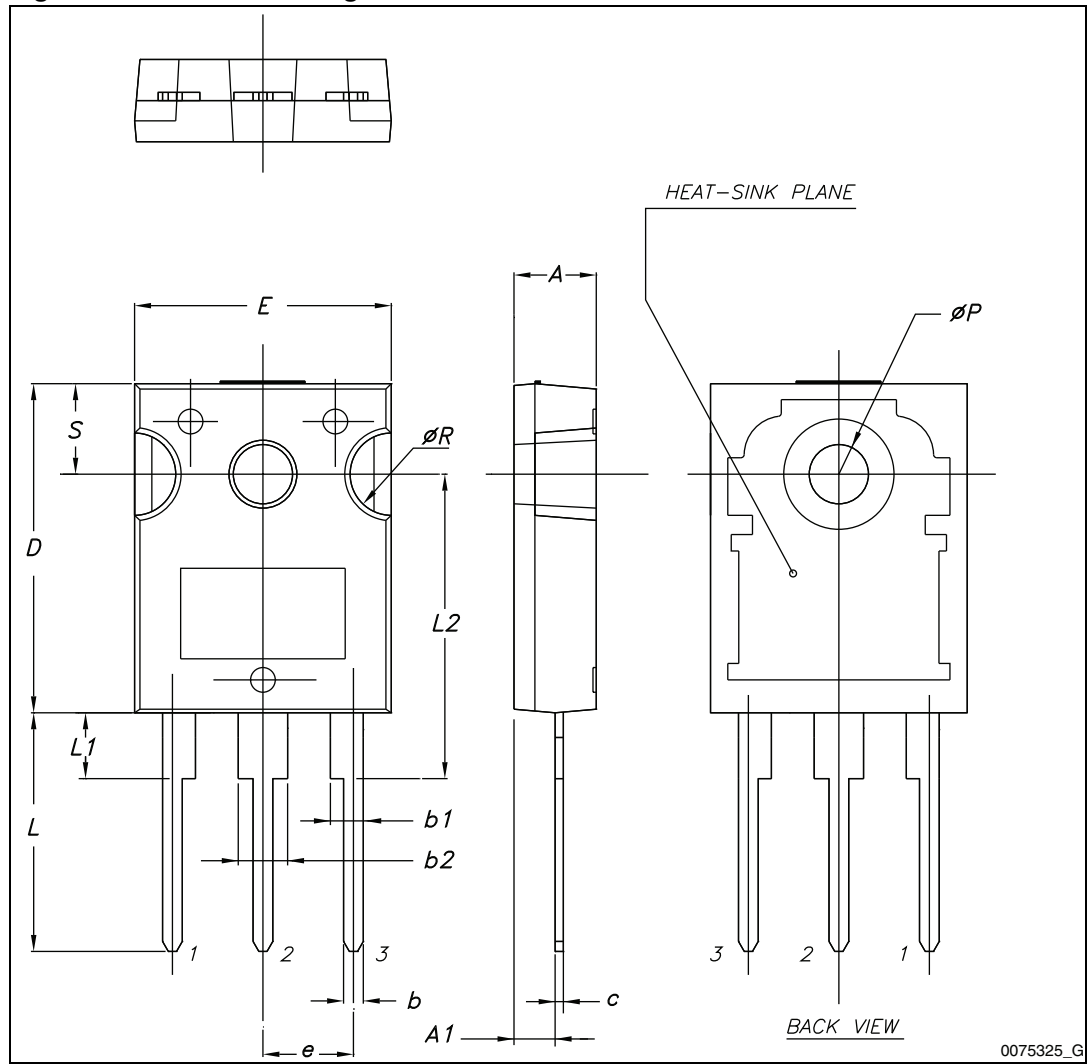
## 5 Package mechanical data

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Table 5. TO-247 mechanical data

Dim.	mm.		
	Min.	Typ.	Max.
A	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
c	0.40		0.80
D	19.85		20.15
E	15.45		15.75
e	5.30	5.45	5.60
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
ØP	3.55		3.65
ØR	4.50		5.50
S	5.30	5.50	5.70

Figure 5. TO-247 drawing





## 6 Revision history

**Table 6. Document revision history**

Date	Revision	Changes
15-Oct-2007	6	Package change from SOT-93 to TO-247.
12-May-2010	7	Technology change from epitaxial base to planar base island.
19-Apr-2012	8	Added: <a href="#">Figure 2: Safe operating area</a> Updated: mechanical data

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